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January 8, 2007



Commissioner for Patents  
Office of Patent Publication  
Attention: Certificates of Correction Branch  
P.O. Box 1450  
Alexandria, VA 22313-1450

**RE: Patent No.:** 7,147,715  
**Application No.:** 10/628,189  
**Inventor:** David Phillip Malta *et al*  
**Issue Date:** December 12, 2006  
**Title:** Growth of Ultra-High Purity Silicon Carbide Crystals  
in an Ambient Containing Hydrogen

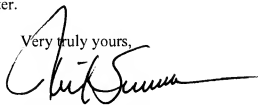
Dear Commissioner:

It is respectfully requested that a Certificate of Correction be issued for the above-referenced patent in accordance with 35 U.S.C. § 254 and 37 C.F.R. § 1.322. This request is made in order to correct mistakes incurred through the fault of the Patent Office.

The errors appearing in Patent No. 7,147,715 are set forth on the attached Certificate of Correction which patentee is electronically filing in accordance with present Patent Office practices.

Thank you for your assistance in this matter.

Very truly yours,



Philip Summa  
Registration No. 31,573

Attachments

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**UNITED STATES PATENT AND TRADEMARK OFFICE  
CERTIFICATE OF CORRECTION**

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PATENT NO. : 7,147,715

APPLICATION NO.: 10/628,189

ISSUE DATE : December 12, 2006

INVENTOR(S) : David Phillip Malta, Jason Ronald Jenny, Hudson McDonald Hobgood, Valeri F. Tsvetkov

It is certified that an error appears or errors appear in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

**In the title page under OTHER PUBLICATIONS:**

**Please add: J.R. JENNY, ST. G. MULLER, A. POWELL, V.F. TSVETKOV, H.MCD. HOBGOOD, R.C. GLASS, & C.H.CARTER; High Purity Semi-Insulating 4H-SiC Grown by the Seeded Sublimation Method; Preprint-2001 Electronic Materials Conference-submitted to Journal of Electronic Materials, U.S.A**

**In the SPECIFICATION**

1. Column 6, line 24, delete "modem" and insert therefor -- "modern" --

**In the CLAIMS**

1. Column 12, line 6, delete "front" and insert therefor -- "from" --
2. Column 12, line 37, delete "send-Insulating" and insert therefor -- "semi-Insulating" --
3. Column 14, line 6, delete "15K" and insert therefor -- "15R" --

**MAILING ADDRESS OF SENDER (Please do not use customer number below):**

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This collection of information is required by 37 CFR 1.322, 1.323, and 1.324. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 1.0 hour to complete, including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, U.S. Department of Commerce, P.O. Box 1450, Alexandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Attention Certificate of Corrections Branch, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

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